

## 15A,600V 单相玻璃钝化整流桥 15A,600V Single Phase Glass Passivated Bridge Rectifier

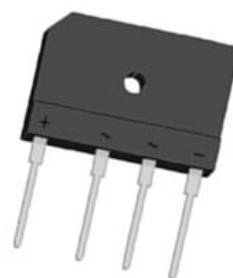
### ■特征 Features

- 玻璃钝化芯片  
Glass passivated chip
- 低反向漏电流  
Low reverse leakage current
- 高耐浪涌电流能力  
High surge current capability
- UL 档案编号# E249161  
UL recognized file # E249161
- 符合 RoHS 指令 2011/65/EU  
Compliant to RoHS directive 2011/65/EU

关键参数 KEY PARAMETERS		
参数 PARAMETER	数值 VALUE	单位 UNIT
$I_{F(AV)}$	15	A
$V_{RRM}$	600	V
$I_{FSM}$	250	A
Package	D-SB-LV	

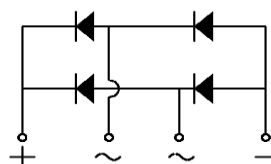
### ■应用范围 Applications

- 家用电器  
Household electric appliances
- 工业电源  
Industrial power supply
- 开关式电源  
Switching mode power supply
- 通用单相桥式整流桥  
General purpose single phase bridge rectifier



### ■机械参数 Mechanical Data

- 本体: D-SB-LV  
Case : D-SB-LV
- 极性: 极性符号铸在管体上  
Polarity: Polarity symbols being marked on body
- 安装扭矩: 8.0kgf.cm  
Mounting torque: 8.0kgf.cm max
- 重量: 约 6.8 克  
Weight : About 6.8 grams



### ■最大额定值 Maximum Ratings @ Ta = 25°C unless otherwise noted

参数 PARAMETER	符号 SYMBOL	D15SB60 LV	单位 UNIT
反向重复峰值电压 Maximum recurrent peak reverse voltage	$V_{RRM}$	600	V
平均整流输出电流 Average rectified output current	$I_{(AV)}$	15	A
最大正向浪涌电流, 8.3ms 单半正弦波叠加在额定负载上 Peak surge forward current, 8.3ms single half sine-wave superimposed on rated load	$I_{FSM}$	250	A
热容值, 1ms<t<8.3ms, Tj=25°C, 单个二极管 Rating for fusing, 1ms<t<8.3ms, Tj=25°C, Rating of per diode	$I^2t$	259	A <sup>2</sup> s
结温 Junction temperature	$T_j$	-55 ~ +150	°C
存储温度 Storage temperature	$T_{STG}$	-55 ~ +150	°C
绝缘耐压, 端子与外壳之间外加交流电 1 分钟 Dielectric strength, terminals to case AC 1 minute	$V_{dis}$	2.5	KV

■电性特性 Electrical Characteristics @ Ta = 25°C unless otherwise noted

参数 PARAMETER	条件 CONDITIONS	符号 SYMBOL	额定值 RATED VALUE	单位 UNIT
正向峰值电压 Peak Forward Voltage	$I_F = 7.5A$	$V_F$	MAX:0.93	V
反向峰值电流 Peak Reverse Current	VR=VRRM, 脉冲测试, 单个二极管的额定值 VR=VRRM, Pulse measurement Rating of per diode	$T_j = 25^\circ C$	5	$\mu A$
		$T_j = 125^\circ C$	500	

■热特性 Thermal Characteristics @ Ta = 25°C unless otherwise noted

参数 PARAMETER	符号 SYMBOL	额定值 RATED VALUE	单位 UNIT
结到环境的热阻, 无散热片 Junction to ambient thermal resistance, without heatsink	$R_{\theta JA}$	22	$^\circ C/W$
结到管壳的热阻, 有散热片 Junction to case thermal resistance, with heatsink	$R_{\theta JC}$	1.5	$^\circ C/W$

■特性曲线 Characteristic Curve

FIG1.Derating Curve For Output Rectified Current

图 1. 电流降额曲线

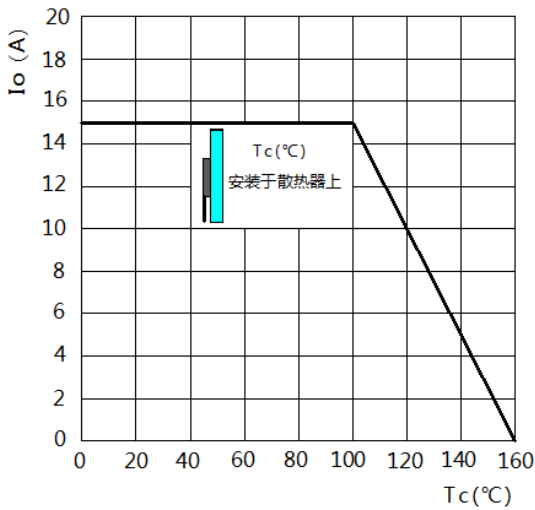


FIG2.Maximum Non-Repetitive Peak Forward Surge Current Per Bridge Element

图 2. 最大正向不重复峰值浪涌电流

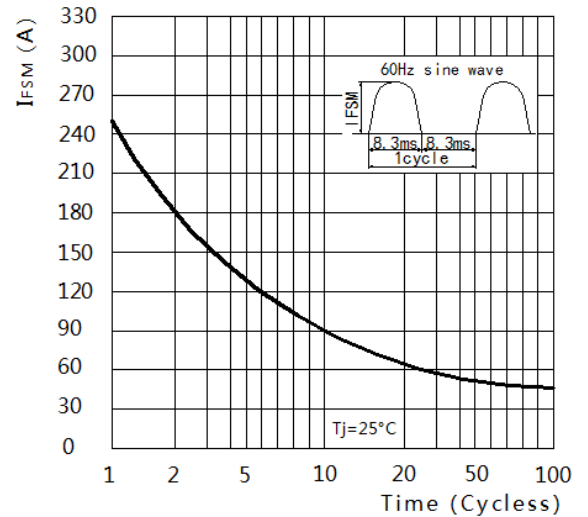


FIG3.Typical Reverse Characteristics Per Bridge Element

图 3. 典型反向特性

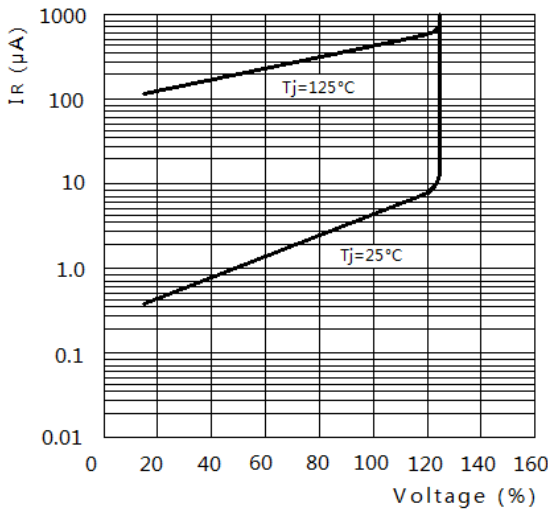
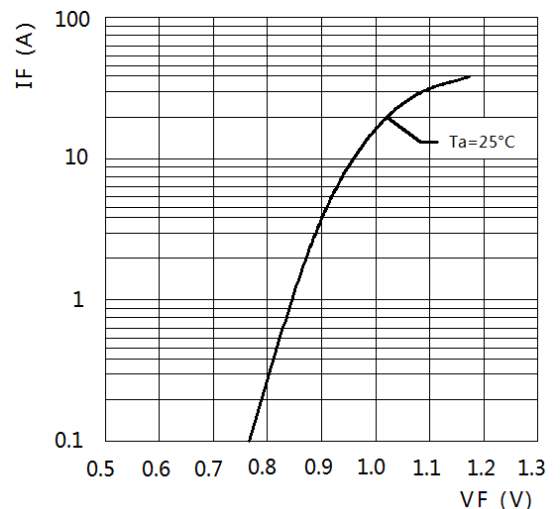
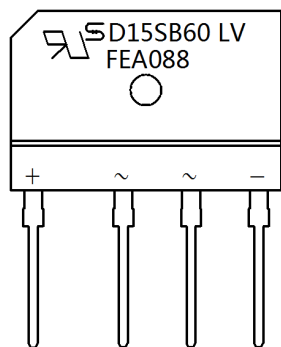


FIG4.Typical Forward Characteristics Per Bridge Element

图 4. 典型正向特性



■ 标记图 Marking Diagram



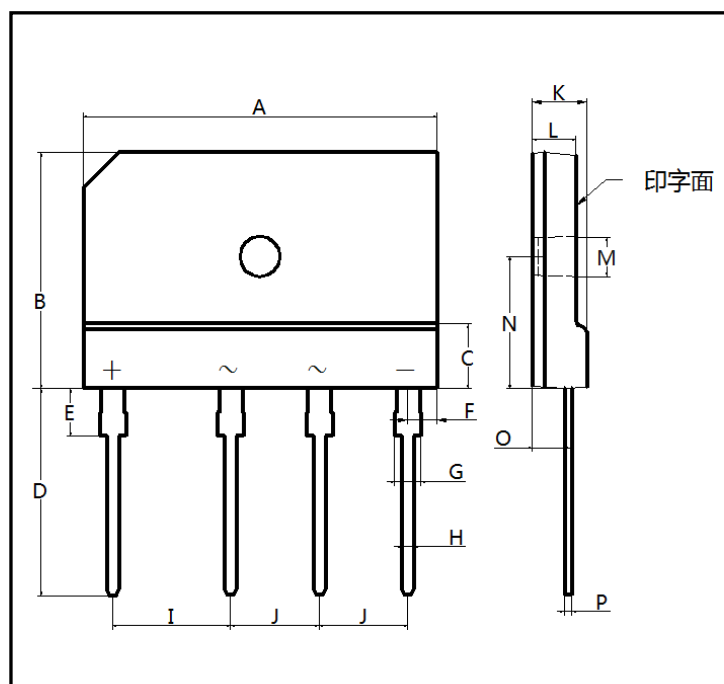
D15SB60 LV : 标识代码

Marking code

FEA088 : 制程码

Process code

■ 尺寸图 Dimension Drawing



Dim.	Unit(mm)		Unit(inch)	
	Min.	Max.	Min.	Max.
A	29.70	30.30	1.169	1.193
B	19.70	20.30	0.776	0.799
C	5.00	6.00	0.197	0.236
D	17.00	18.00	0.669	0.709
E	3.50	4.50	0.138	0.177
F	2.30	2.70	0.091	0.106
G	2.00	2.40	0.079	0.094
H	0.90	1.10	0.035	0.043
I	9.80	10.20	0.386	0.402
J	7.30	7.70	0.287	0.303
K	4.40	4.80	0.173	0.189
L	3.40	4.00	0.134	0.157
M	3.10	3.70	0.122	0.146
N	10.90	11.50	0.429	0.453
O	2.50	2.90	0.098	0.114
P	0.55	0.75	0.022	0.030

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